



NPN General Purpose Switching Transistor

Voltage

40V

Current

600mA

Features

- NPN epitaxial Silicon, Planar Design
- Collector-emitter voltage VCE = 40V
- Collector current = 600mA
- Lead free in compliance with EU RoHS2.0 (2011/65/EU & 2015/865/EU directive)
- Green molding compound as per IEC61249 Std.. (Halogen Free)

Mechanical Data

• Case: SOT-89 Package

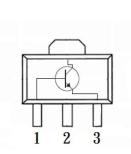
• Terminals: Solderable per MIL-STD-750, Method 2026

• Approx. Weight: 0.002 ounces, 0.057grams

Marking: C2H

SOT-89





Pin Assignment: 1. Base

2. Collector

3. Emitter

Maximum Ratings and Thermal Characteristics (T_A =25 $^{\circ}$ C unless otherwise noted)

PARAMETER	SYMBOL	LIMIT	UNITS
Collector-Base Voltage	V _{CBO}	75	V
Collector-Emitter Voltage	V _{CEO}	40	V
Emitter-Base Voltage	V _{EBO}	6	V
Collector Current (DC)	I _C	600	mA
Collector Current (Pulse)	I _{CP}	800	mA
Total Power Dissipation	Ртот	1.1	W
Junction to Ambient (Note1)	$R_{\theta JA}$	250	°C/W
Operating Junction and Storage Temperature Range	T_{J} , T_{STG}	-55~150	°C

Note1: Transistor mounted on a FR4 PCB, single-sided copper, tin-plated and standard footprint.





Electrical Characteristics (T_A=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
OFF Characteristics						
Collector-Emitter Breakdown Voltage	BV _{CEO}	I _C = 1.0mA, I _B = 0A	40	-	-	V
Collector-Base Breakdown Voltage	BV _{CBO}	$I_C=10uA$, $I_E=0A$	75	-	-	V
Emitter-Base Breakdown Voltage	BV _{EBO}	I _E = 10uA, I _C = 0A	6	-	-	V
Collector-Base Cutoff Current	I _{CBO}	$V_{CB} = 60V, I_{E} = 0A$	-	-	10	nA
Emitter-Base Cutoff Current	I _{EBO}	V _{EB} = 3V	-	-	10	nA
Collector-Emitter Cutoff Current	I _{CES}	V _{CES} = 60V	-	-	10	nA
ON characteristics						
DC Current Gain	h _{FE}	$V_{CE} = 10V I_{C} = 0.1 mA$	35	-	-	- - -
		V_{CE} = 10V I_{C} = 1mA	50	-	-	
		V _{CE} = 10V I _C = 10mA	75	-	-	
		V _{CE} = 10V I _C = 150mA	100	-	300	
		V _{CE} = 1V I _C = 150mA	50	-	-	
		V _{CE} = 10V I _C = 500mA	40	-	-	
Collector-Emitter Saturation Voltage	V _{CE(SAT)}	I _C = 150mA, I _B = 15mA	-	-	0.3	V
		I _C = 500mA, I _B = 50mA	-	-	1.0	
Base-Emitter Saturation voltage	V _{BE(SAT)}	I _C = 150mA, I _B = 15mA	-	-	1.2	V
		I _C = 500mA, I _B = 50mA	1	-	2.0	
Collector-Base Capacitance	C _{CBO}	V _{CB} = 10V, f=1MHz	-	-	8	
Emitter-Base Capacitance	C _{EBO}	V _{CB} = 0.5V, f=1MHz	-	-	25	pF
Delay Time	td	VCC= 3V, VBE= -5V	-	-	10	
Rise Time	tr	IC= 150mA, IB= 15mA	-	-	25	nS
Storage Time	ts	VCC= 30V, IC= 150mA	-	-	225	
Fall Time	tf	IB1 = IB2 = 15mA	-	-	60	
Turn-on Time	ton	IC= 150mA,Ibon =15mA	-	-	35	
Turn-off Time	toff	Iboff = -15mA	-	-	250	
Transition Frequency	fT	VCE = 10 V; IC = 20mA F = 100 MHz	300	-	-	MHz





TYPICAL CHARACTERISTIC CURVES

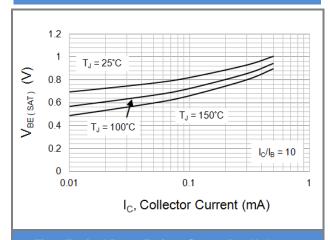


Fig.1 Typical Base-Emitter Saturation Voltage

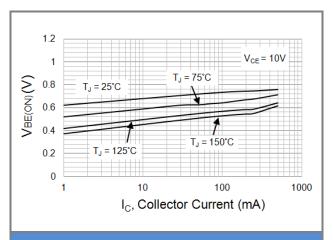


Fig.2 Typical Base-Emitter Turn-on Voltage

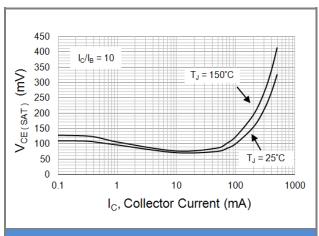
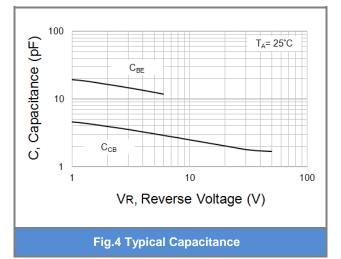


Fig.3 Typical Collector-Emitter Saturation



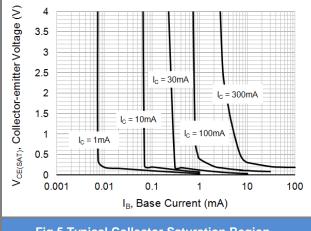


Fig.5 Typical Collector Saturation Region

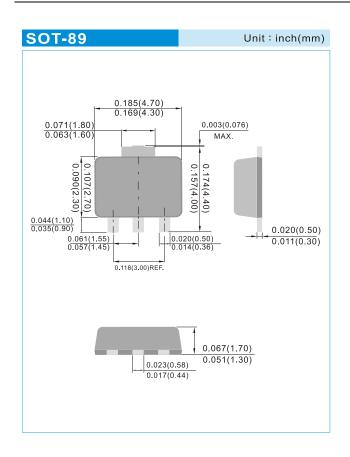


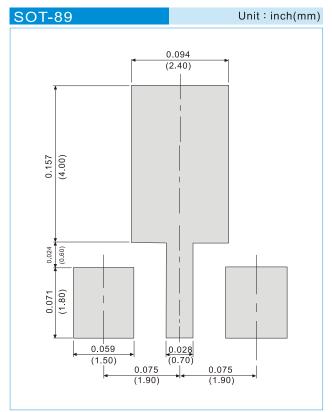


Part No Packing Code Version

Part No Packing Code	Package Type	Packing Type	Marking	Version
2SC2222H_R1_00001	SOT-89	1000pcs / 7" reel	C2H	Halogen free

Packaging Information & Mounting Pad Layout









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